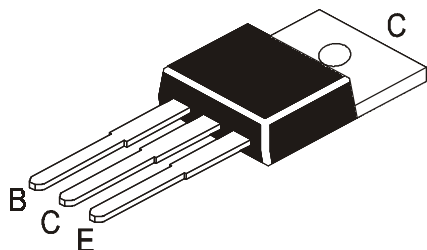


SILICON EPITAXIAL POWER TRANSISTORS

MJE15032 NPN
MJE15033 PNP

TO - 220
Plastic Package



High- Frequency Drivers in Audio Amplifier.

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Base Voltage	V_{CBO}	250	V
Collector Emitter Voltage	V_{CEO}	250	V
Emitter Base Voltage	V_{EBO}	5	V
Collector Current - Continuous	I_C	8	A
- Peak		16	A
Base Current	I_B	2	A
Total Power Dissipation @ $T_C=25^\circ\text{C}$	P_D	50	W
Derate Above 25°C		0.4	W/ $^\circ\text{C}$
Total Power Dissipation @ $T_A=25^\circ\text{C}$	P_D	2	W
Derate Above 25°C		0.016	W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_j, T_{stg}	-65 to +150	$^\circ\text{C}$

THERMAL RESISTANCE

From Junction to Ambient	$R_{th(j-a)}$	62.5	$^\circ\text{C/W}$
From Junction to Case	$R_{th(j-c)}$	2.5	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter sustaining Voltage	$V_{CEO(sus)}$ *	$I_C=10\text{mA}, I_B=0$	250	-	V
Collector Cut off Current	I_{CBO}	$V_{CB}=150\text{V}, I_E=0$	-	10	μA
Emitter Cut off Current	I_{EBO}	$V_{BE}=5\text{V}, I_C=0$	-	10	μA
DC Current Gain	h_{FE} *	$I_C=0.5\text{A}, V_{CE}=5\text{V}$	50	-	
		$I_C=1.0\text{A}, V_{CE}=5\text{V}$	50	-	
		$I_C=2.0\text{A}, V_{CE}=5\text{V}$	10	-	
Collector Emitter Saturation Voltage	$V_{CE(sat)}$ *	$I_C=1\text{A}, I_B=0.1\text{A}$	-	0.5	V
Base Emitter on Voltage	$V_{BE(on)}$ *	$I_C=1.0\text{A}, V_{CE}=5\text{V}$	-	1.0	V

DYNAMIC CHARACTERISTICS

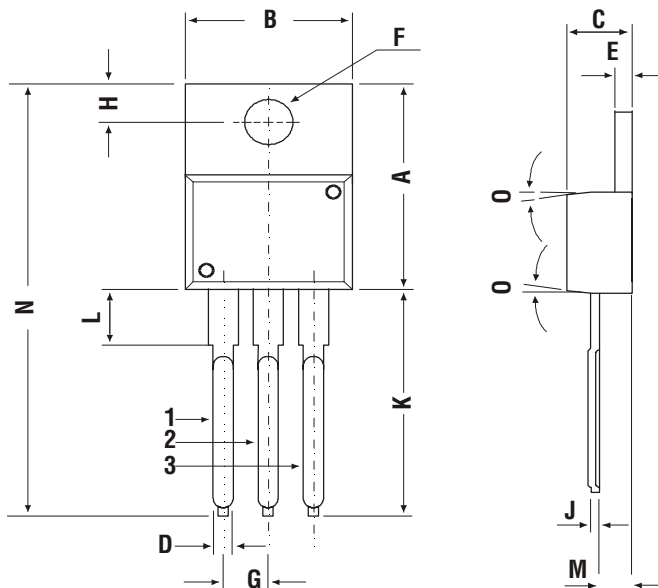
Current Gain - Bandwidth Product **	f_T	$I_C=500\text{mA}, V_{CE}=10\text{V}$ $f_{test}=1\text{MHz}$	30	-	MHz
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* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

** $f_T = I_{h_{FE}} / f_{test}$

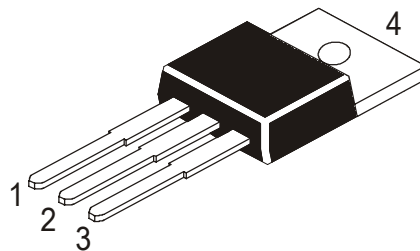
TO - 220
Plastic Package

TO-220 Plastic Package



DIM	MIN	MAX
A	14.42	16.51
B	9.63	10.67
C	3.56	4.83
D	—	0.90
E	1.15	1.40
F	3.75	3.88
G	2.29	2.79
H	2.54	3.43
J	—	0.56
K	12.70	14.73
L	2.80	4.07
M	2.03	2.92
N	—	31.24
O	7 DEG	

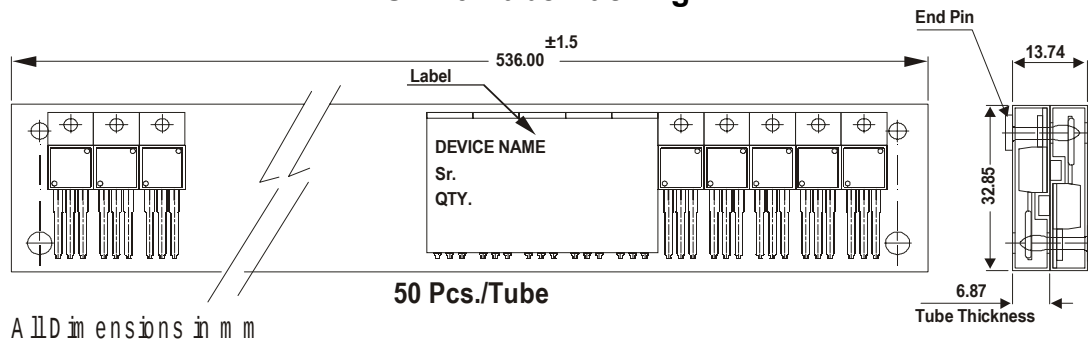
All dimensions in mm.



Pin Configuration

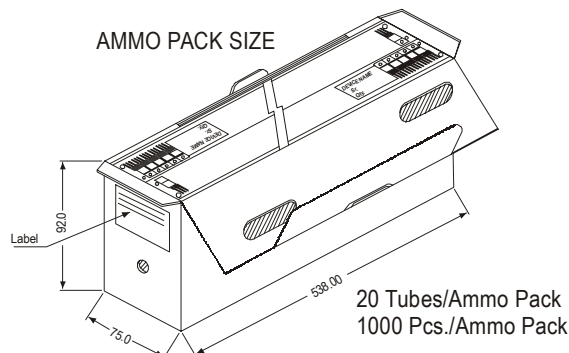
1. Base
2. Collector
3. Emitter
4. Collector

TO-220 Tube Packing



All dimensions in mm

AMMO PACK SIZE



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-220	200 pcs/polybag	396 gm/200 pcs	3" x 7.5" x 7.5"	1K	17" x 15" x 13.5"	16K	36 kgs
	50 pcs/tube	135 gm/50 pcs	3.5" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	28 kgs

Disclaimer

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Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290

e-mail sales@cdil.com www.cdil.com